

BLACK SAND TECHNOLOGIES ANNOUNCES WORLD'S FIRST 3G CMOS RF POWER AMPLIFIER

CLOSES \$10M SERIES B FINANCING

AUSTIN, Texas — Sep. 8, 2009 — Black Sand Technologies, Inc., a fabless semiconductor company specializing in advanced power amplifier technology for wireless applications, today announced that it has produced the world's first 3G CMOS RF Power Amplifier (PA). Black Sand's proprietary CMOS PA architecture offers a breakthrough in combined performance, cost, battery life, and reliability for mobile devices such as mobile phones and datacards. The company also announced today that it has received US\$10 million in its second round of funding. The round was led by Northbridge Venture Partners and joined by Austin Ventures, bringing the total investment in the company to US\$18.2 million. Black Sand will use the funding to bring its power amplifiers into mass production and accelerate development of additional products.

Black Sand's RF PA products are targeted at mobile phones and other 3G wireless devices, such as datacards and netbooks. Mobile phones and wireless products today use power amplifiers based on Gallium Arsenide (GaAs) semiconductor technology. Replacing GaAs with CMOS silicon technology improves manufacturing yield, performance, cost, battery life, and call quality.

Over time CMOS has replaced GaAs technology in many other applications from audio chips to DVD decoders. However, CMOS does not lend itself easily to use in power amplifiers, so a revolutionary architecture was required. "By leveraging our breakthrough PA architecture, Black Sand, as the first company to deliver 3G PAs in CMOS, is ready to capitalize on the historic shift from GaAs to CMOS, and benefit from the explosion in demand for new 3G devices appearing on the market today," said John Diehl, CEO of Black Sand Technologies.

Commenting of the potential market for this technology, Stan Bruederle, Research Vice President, Semiconductor Applications Research, Gartner, Inc., affirmed, "3G mobile phones typically have more power amplifiers than 2G or 2.5G phones.. As an example, the iPhone, a 2.5G phone has one cellular power amplifier package in it while the iPhone 3G has five cellular power amplifier packages in it. Gartner estimates that by 2013 sixty percent of mobile phone sales will be 3G UMTS handsets."

"The RF front end of mobile phones is continuing to grow in complexity and with the development of linear, 3G CMOS PA technology, enabling advances such as integrated digital control circuits, Black Sand

is in a unique position to profit from this technological shift as the market moves from 2G to 3G," added

Brian Modoff, Senior Wireless Equipment Analyst at Deutsche Bank.

"We were impressed to see that Black Sand delivered working samples of their new PA architecture much

sooner than expected." said Basil Horangic, Partner at Northbridge Venture Partners. "This is a very

competitive market and Black Sand's linear PA architecture puts them out in front. Their unique offering

will provide the basis for a broad portfolio of products from 2G to 4G." Krishna Srinivasan, Partner at

Austin Ventures added, "Since inception this team has executed in hitting milestones and developing new,

world-class IP, and we are delighted to continue our support for the company as they enter a new phase of

growth."

"Black Sand is extremely pleased with this up-round of financing that we've received. Our company is

now well positioned to take these products to market by providing a new level of integrated cost and

performance to our customers" concluded Diehl.

Notes to editors:

Gartner's analysis based on the following reports:

Dataquest Insight: Teardown Reveals iPhone System Design Mixes Innovation and Compromise - July '07

Dataquest Insight: List of Semiconductor Components in Apple's iPhone 3G – September '08

Forecast: Mobile Devices, Worldwide, 2003-2013 - March '09

About Black Sand Technologies:

Founded in 2005, Black Sand Technologies, Inc. is a fabless semiconductor company dedicated to building

solutions for the wireless industry by combining sensitive analog and powerful digital circuits in silicon.

Black Sand's unique combination of patented mixed-signal technology and industry experience will lead

the way to new levels of cost and performance in wireless products of the future. Black Sand is based in

Austin, Texas, and is funded by Austin Ventures and Northbridge Venture Partners. For more information,

please visit www.blacksand.com.

#

Black Sand Technologies and the Black Sand logo are a trademarks of Black Sand Technologies, Inc.

For More Information, Please Contact:

Black Sand Technologies, Inc. Jim Nohrden, 512-329-9400 x202

VP Marketing

jmn@blacksand.com